

SMD Schottky Barrier Diode

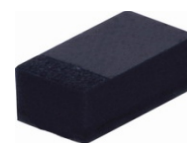


SMD Diodes Specialist

CDBFR0230L(RoHs Device)

$I_o = 200 \text{ mA}$

$V_R = 30 \text{ Volts}$

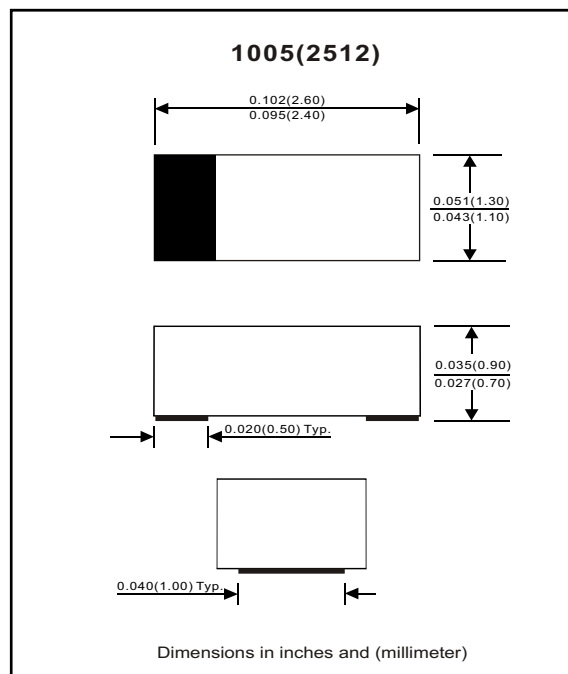


Features

- Low forward voltage.
- Designed for mounting on small surface.
- Extremely thin / leadless package.
- Majority carrier conduction.

Mechanical data

- Case: 1005(2512) standard package molded plastic.
- Terminals: Gold plated, solderable per MIL-STD-750,method 2026.
- Polarity: Indicated by cathode band.
- Mounting position: Any
- Weight: 0.006 gram(approx.).



Maximum Rating (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Repetitive peak reverse voltage		V_{RRM}			35	V
Reverse voltage		V_R			30	V
Average forward current		I_o			200	mA
Forward current,surge peak	8.3ms single half sine-wave superimposed on rate load(JEDEC method)	I_{FSM}			1	A
Storage temperature		T_{STG}	-40		+125	$^{\circ}\text{C}$
Junction temperature		T_j			+125	$^{\circ}\text{C}$

Electrical Characteristics (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 200 \text{ mA}$	V_F			0.5	V
Reverse current	$V_R = 10 \text{ V}$	I_R			30	μA

RATING AND CHARACTERISTIC CURVES (CDBFU0230L)

Fig. 1 - Forward characteristics

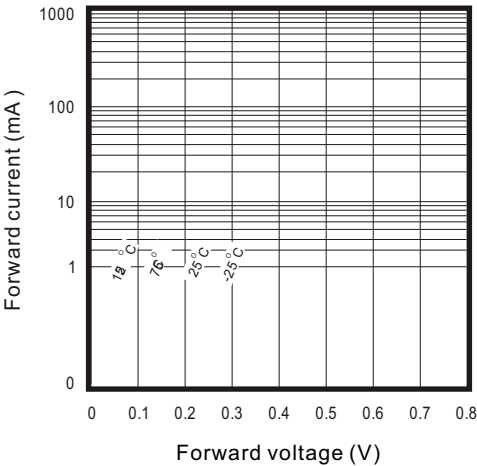


Fig. 2 - Reverse characteristics

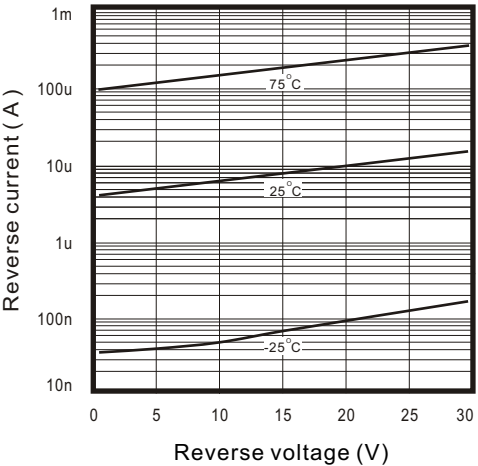


Fig.3 - Capacitance between terminals characteristics

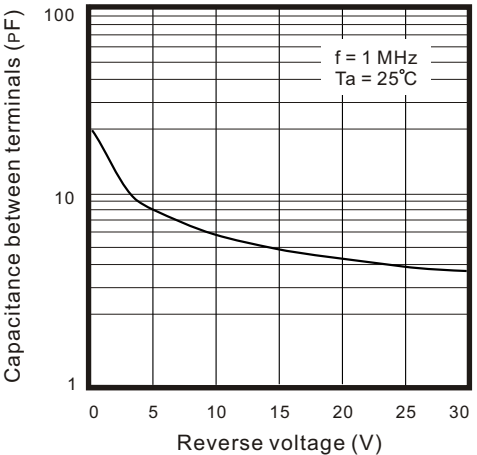


Fig.4 - Current derating curve

